

NPN PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR

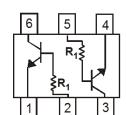
Features

- Epitaxial Planar Die Construction
- · Built-In Biasing Resistors
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)



Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)



Device Schematic

SOT363



Top View

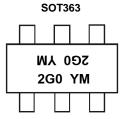
Ordering Information (Note 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ADC113TUQ-7	Automotive	2G0	7	8	3,000
ADC113TUQ-13	Automotive	2G0	13	8	10,000

Notes

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



2G0 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Year	2018	2019	2020	2021	202	2 20)23	2024	2025	2026	2027	2028
Code	F	G	Н	- 1	J		K	L	М	N	0	Р
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I _C (Max)	100	mA

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 6 & 7)	P_{D}	270	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{ heta JA}$	450	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

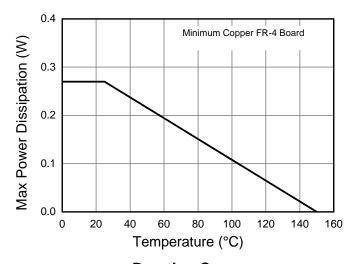
Notes:

^{6.} Mounted on FR-4 PC Board with minimum recommended pad layout.

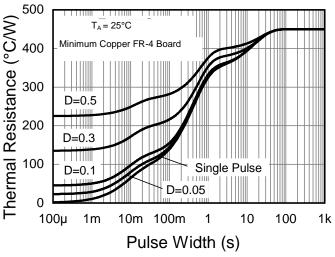
^{7. 150}mW per element must not be exceeded.



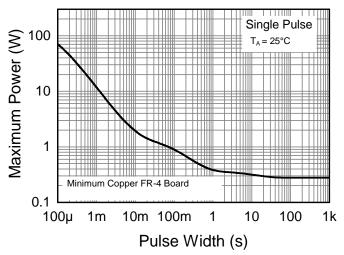
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation



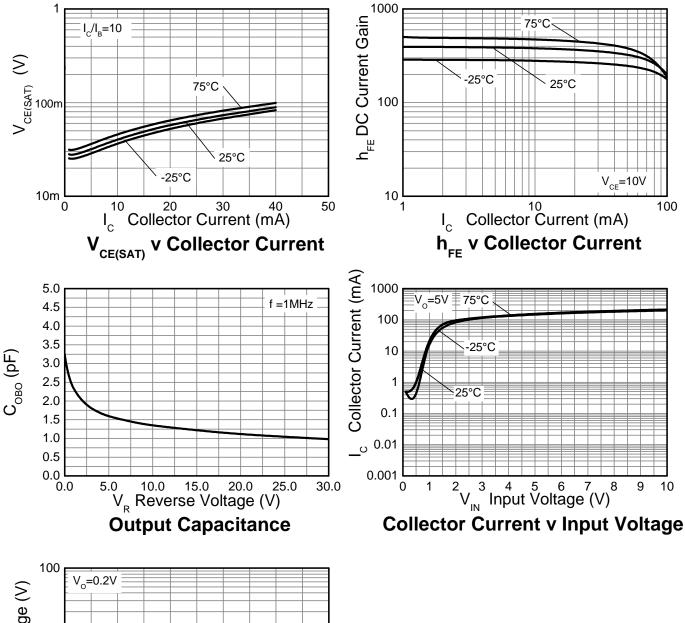
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

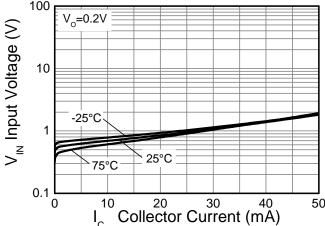
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	50	_	_	V	$I_C = 50\mu A$
Collector-Emitter Breakdown Voltage	BV _{CEO}	50	_		V	$I_C = 1mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	5	_	_	V	$I_E = 50\mu A$
Collector Cutoff Current	I _{CBO}		_	0.5	μΑ	$V_{CB} = 50V$
Emitter Cutoff Current	I _{EBO}	_	_	0.5	μΑ	$V_{EB} = 4V$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		_	0.3	V	$I_{C}/I_{B} = 10\text{mA}/1\text{mA}$
DC Current Transfer Ratio	h _{FE}	100	250	600	_	$I_C = 1mA$, $V_{CE} = 5V$
Input Resistor (R ₁) Tolerance	ΔR_1	-30		+30	%	
Gain-Bandwidth Product (Note 8)	f _T	_	250	_	MHz	$V_{CE} = 10V, I_{E} = -5mA, f = 100MHz$

Note: 8. Transistor - For Reference Only.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





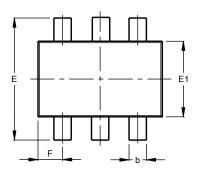
Input Voltage v Collector Current

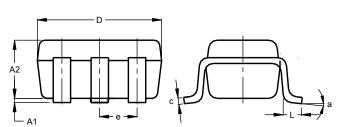


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



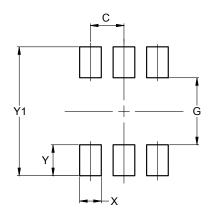


SOT363						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.10	0.30	0.25			
C	0.10	0.22	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	0.650 BSC					
F	0.40	0.45	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value (in mm)		
С	0.650		
G	1.300		
Х	0.420		
Υ	0.600		
Y1	2.500		



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